

Reference Module - SE Series

The SE Series utilizes Seoul's flagship high efficacy 5630 LEDs to deliver efficacies up to 189 Lm/W at typical driving currents. This solution features uniformity of light and color and enables easy installation with a Zhaga compatible mounting pattern.

Applications:



Features:

- High efficacy, long life
- Industry standard mechanical attributes
- Optimized for industry standard power supplies
- 3 SDCM
- ROHS Compliant

Key Applications:

- Troffer Retrofit
- High Bay
- LED Panel
- Channel

Product Selection: SMJD-3607024B-XXN1 $I_F = 200\text{mA}$, $T_C = 25^\circ\text{C}$

CCT	CRI	Flux		Dimension	Order Code
		Min.	Typ.		
3000	80	1170	1260	560*20	SMJD-3607024B-XXN100B26G038AII
3500					SMJD-3607024B-XXN100B26F038AII
4000		1210	1300		SMJD-3607024B-XXN100B30E038AII
5000					SMJD-3607024B-XXN100B30C038AII

Product Selection: SMJD-3614048B-XXN1 $I_F = 400\text{mA}$, $T_C = 25^\circ\text{C}$

CCT	CRI	Flux		Dimension	Order Code
		Min.	Typ.		
3000	80	2350	2530	560*20	SMJD-3614048B-XXN100C53G038AII
3500					SMJD-3614048B-XXN100C53F038AII
4000		2420	2600		SMJD-3614048B-XXN100C60E038AII
5000					SMJD-3614048B-XXN100C60C038AII

Product Selection: SMJD-3621072B-XXN1 $I_F = 600\text{mA}$, $T_C = 25^\circ\text{C}$

CCT	CRI	Flux		Dimension	Order Code
		Min.	Typ.		
3000	80	3520	3790	560*20	SMJD-3621072B-XXN100D79G038AII
3500					SMJD-3621072B-XXN100D79F038AII
4000		3640	3910		SMJD-3621072B-XXN100D91E038AII
5000					SMJD-3621072B-XXN100D91C038AII

Electro Optical Characteristics: SMJD-3607024B-XXN1 $I_F = 200\text{mA}$, $T_C = 25^\circ\text{C}$

Parameter	Symbol	Value			Unit	Remark
		Min.	Typ.	Max.		
Luminous Flux	$\Phi_V^{[2]}$	1170	1260	-	lm	F,G
		1210	1300	-		C,E
Correlated Color Temperature ^[3]	CCT	4745	5028	5311	K	C
		3710	3985	4260		E
		3200	3500	3700		F
		2870	3045	3220		G
CRI	Ra	80	-	-	-	-
Input Voltage	V_F	33.6	34.5	35.4	V_{DC}	@200mA
Power Consumption	P	6.7	6.9	7.1	W	
Efficiency	LPW	-	183	-	lm/W	F,G
		-	189	-		C,E

Electro Optical Characteristics: SMJD-3614048B-XXN1 $I_F = 400\text{mA}$, $T_C = 25^\circ\text{C}$

Parameter	Symbol	Value			Unit	Remark
		Min.	Typ.	Max.		
Luminous Flux	$\Phi_V^{[2]}$	2350	2530	-	lm	F,G
		2420	2600	-		C,E
Correlated Color Temperature ^[3]	CCT	4745	5028	5311	K	C
		3710	3985	4260		E
		3200	3500	3700		F
		2870	3045	3220		G
CRI	Ra	80	-	-	-	-
Input Voltage	V_F	33.6	34.5	35.4	V_{DC}	@400mA
Power Consumption	P	13.4	13.8	14.2	W	
Efficiency	LPW	-	183	-	lm/W	F,G
		-	189	-		C,E

Notes:

- 1 Above data tested with constant typical current at $T_C = 25^\circ\text{C}$.
- 2 Φ_V is the total luminous flux output measured with an integrated sphere.
- 3 Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- 4 To use the module properly, recommend to drive the module by a Constant Current Source (CCS). But the Maximum output voltage of the CCS should be limited by referring this sheet.

Electro Optical Characteristics: SMJD-3621072B-XXN1 $I_F = 600\text{mA}$, $T_C = 25^\circ\text{C}$

Parameter	Symbol	Value			Unit	Remark
		Min.	Typ.	Max.		
Luminous Flux	$\Phi_v^{[2]}$	3520	3790	-	lm	F,G
		3640	3910	-		C,E
Correlated Color Temperature ^[3]	CCT	4745	5028	5311	K	C
		3710	3985	4260		E
		3200	3500	3700		F
		2870	3045	3220		G
CRI	Ra	80	-	-	-	-
Input Voltage	V_F	33.6	34.5	35.4	V_{DC}	@600mA
Power Consumption	P	20.2	20.7	21.2	W	
Efficiency	LPW	-	183	-	lm/W	F,G
		-	189	-		C,E

Absolute Maximum Operating Specification: $T_C = 25^\circ\text{C}$

Model	Parameter	Symbol	Unit	Value	Remark
SMJD-3607024B-XXN1	Power Consumption	P	W	11.3	
	Forward Voltage	V_F	V	37.7	
	Driving Current ⁽²⁾	I_F	mA	300	
SMJD-3614048B-XXN1	Power Consumption	P	W	22.6	
	Forward Voltage	V_F	V	37.7	
	Driving Current ⁽²⁾	I_F	mA	600	
SMJD-3621072B-XXN1	Power Consumption	P	W	33.9	
	Forward Voltage	V_F	V	37.7	
	Driving Current ⁽²⁾	I_F	mA	900	
All	Operating Temperature ⁽³⁾	T_C	$^\circ\text{C}$	- 40 ~ 85	Reference point
	Storage Temperature	T_{stg}	$^\circ\text{C}$	- 40 ~ 100	With no power
	Thermal resistance (T_C to base)	$R_{th(T_C\text{-base})}$	$^\circ\text{C/W}$	0.3	
	ESD Sensitivity	-	KV	± 8	IEC Air
				± 4	HBM

Notes:

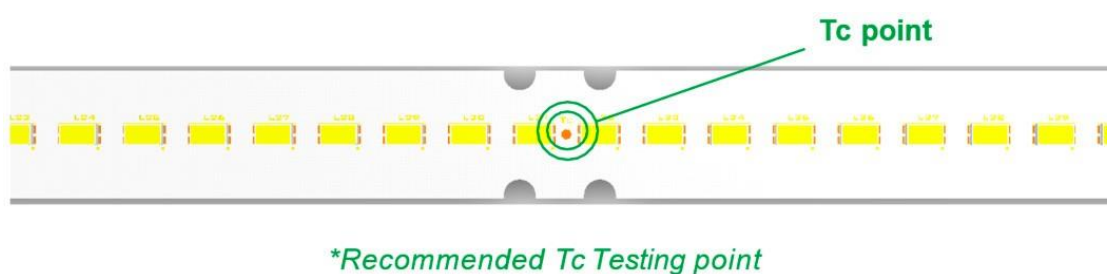
- 1 Above data tested with constant typical current at $T_C = 25^\circ\text{C}$.
- 2 Φ_v is the total luminous flux output measured with an integrated sphere.
- 3 Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- 4 To use the module properly, recommend to drive the module by a Constant Current Source (CCS). But the Maximum output voltage of the CCS should be limited by referring this sheet.

Notes:

*Colors fully compliant with the CIE requested color temperatures on the following table:

Correlated Color Temperature	Nominal CCT	CCT (K)
C	5000 K	5028 ± 283
E	4000 K	3985 ± 275
F	3500 K	3465 ± 245
G	3000 K	3045 ± 175

Illustration: How to predict components temperature

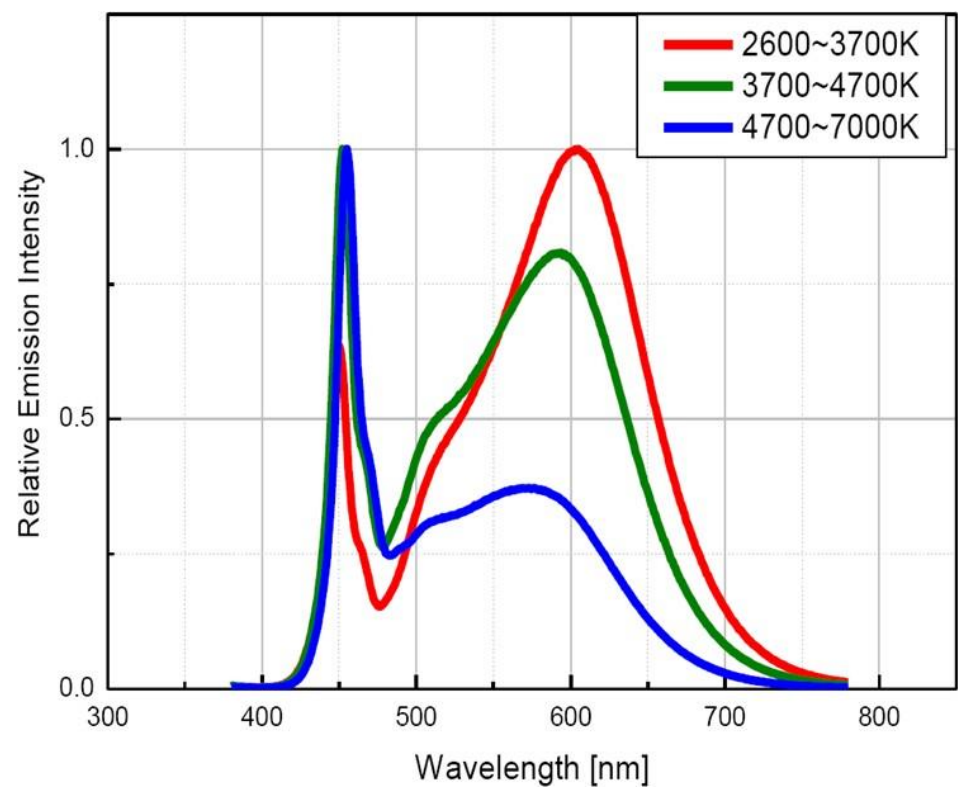


Notes:

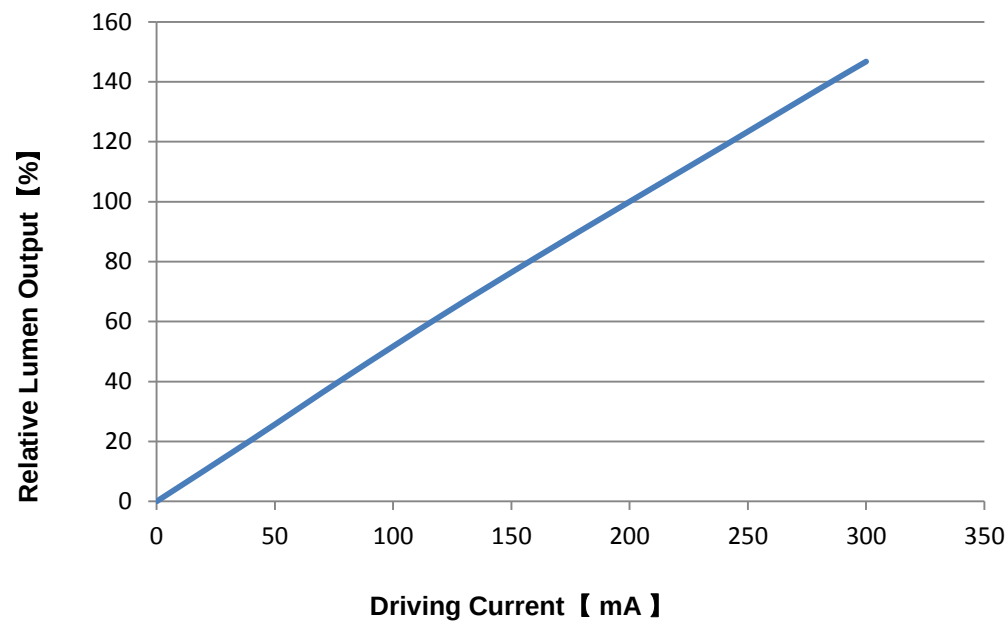
- 1 The modules must be operated within the operating conditions stated in the Absolute Maximum Operating Specifications.
- 2 Please use a Constant Current Source (CCS) to drive the module, the typical V_F of module is 34.5 VDC and V_{F_MAX} is 35.4 VDC, respectively.
- 3 Operating temperature was tested at the assigned T_c point on the PCB.
- 4 To ensure the module works properly, T_c should refer to "Absolute Maximum Operating Specification".

Relative Spectral Distribution

- Relative Spectral Distribution vs. Wavelength

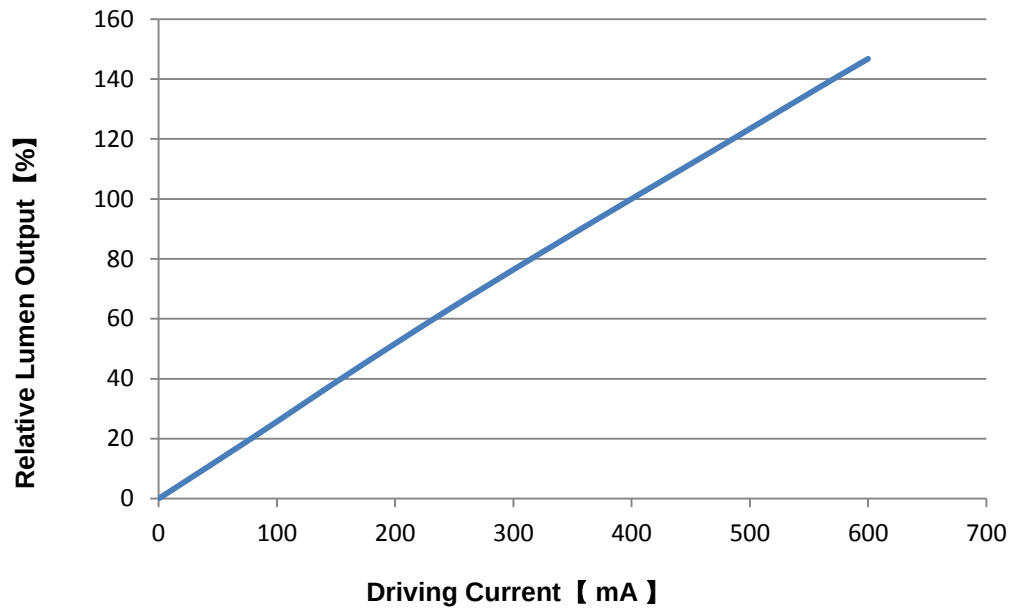


Scale ratio curve for related lumen output VS driving current, $T_c=25^{\circ}\text{C}$
SMJD-3607024B-XXN1



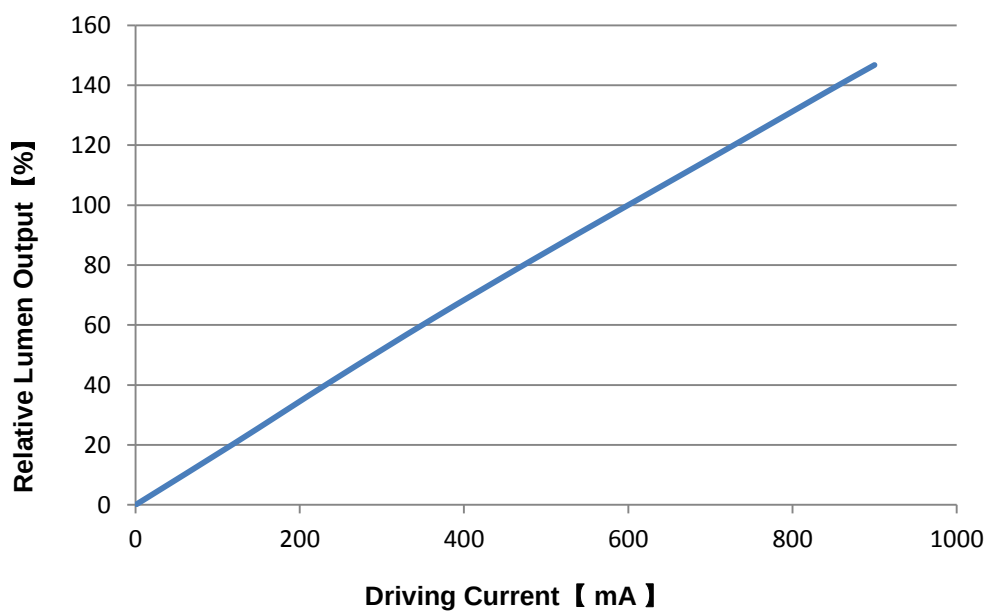
Scale ratio curve for related lumen output VS driving current, $T_C=25^{\circ}\text{C}$

SMJD-3614048B-XXN1



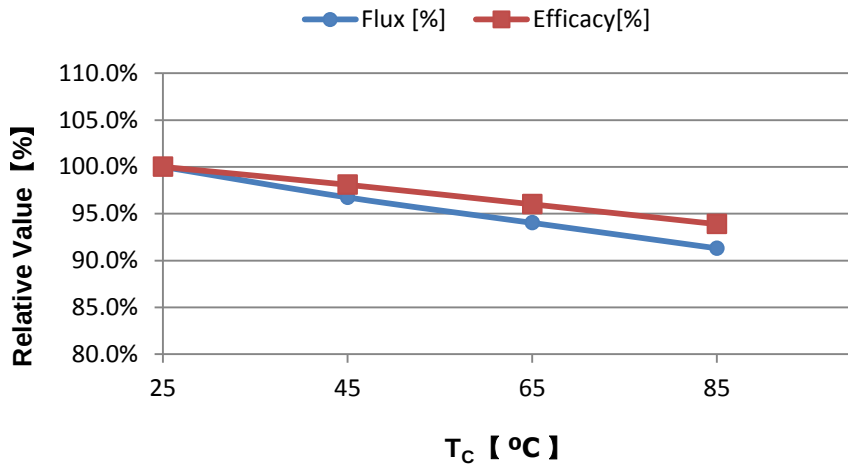
Scale ratio curve for related lumen output VS driving current, $T_C=25^{\circ}\text{C}$

SMJD-3621072B-XXN1



Flux and Efficacy Versus Temperature at T_C (at I_F nominal)

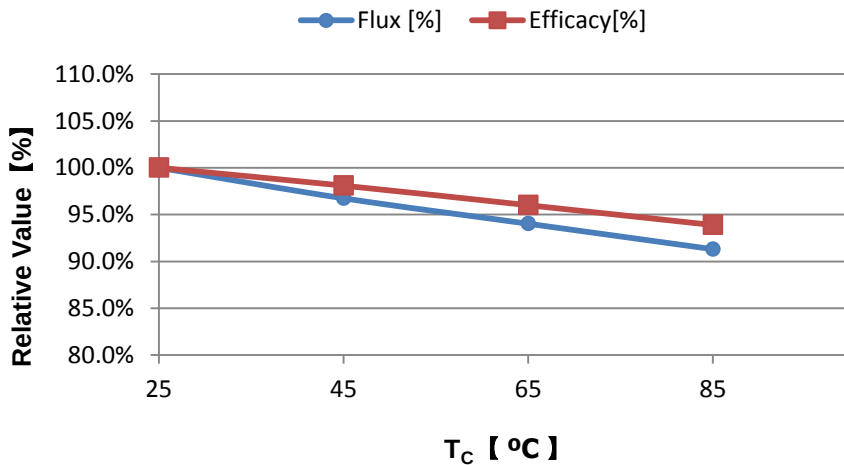
SMJD-3607024B-XXN1, $I_F = 200\text{mA}$



TC [°C]	Flux[%]	Efficacy[%]
25	100	100
45	96.74	98.09
65	94.02	96.00
85	91.30	93.89

Flux and Efficacy Versus Temperature at T_C (at I_F nominal)

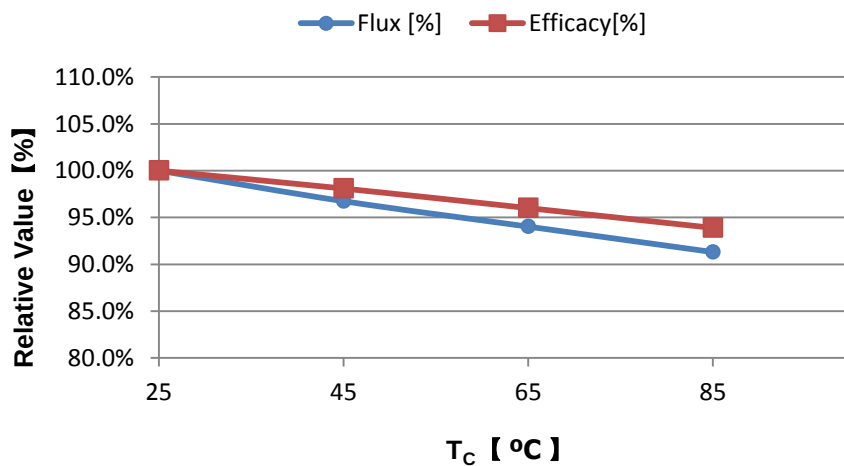
SMJD-3614048B-XXN1, $I_F = 400\text{mA}$



TC [°C]	Flux[%]	Efficacy[%]
25	100	100
45	96.74	98.09
65	94.02	96.00
85	91.30	93.89

Flux and Efficacy Versus Temperature at T_C (at I_F nominal)

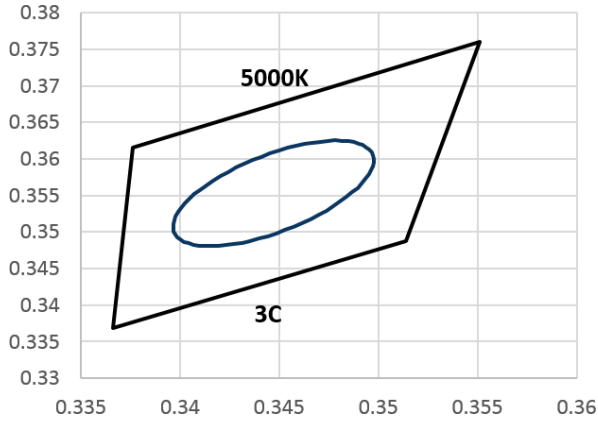
SMJD-3621072B-XXN1, $I_F = 600\text{mA}$



TC [°C]	Flux[%]	Efficacy[%]
25	100	100
45	96.74	98.09
65	94.02	96.00
85	91.30	93.89

Color Bin Structure

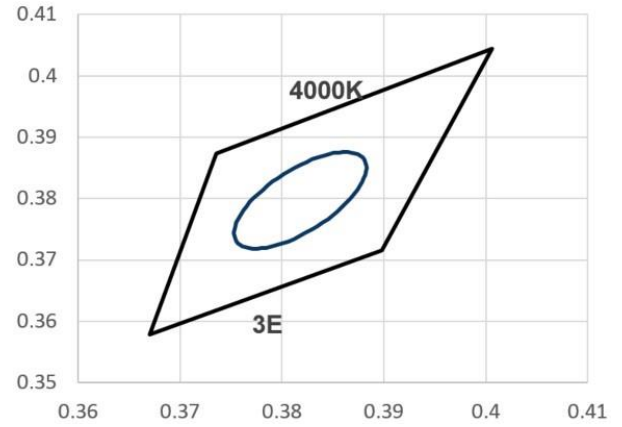
CIE Chromaticity Diagram (Cool white), $T_c=25^\circ\text{C}$



5000K 3 Step Ellipse

3C				
x	y	a	b	theta
0.3447	0.3553	0.0081	0.0035	60

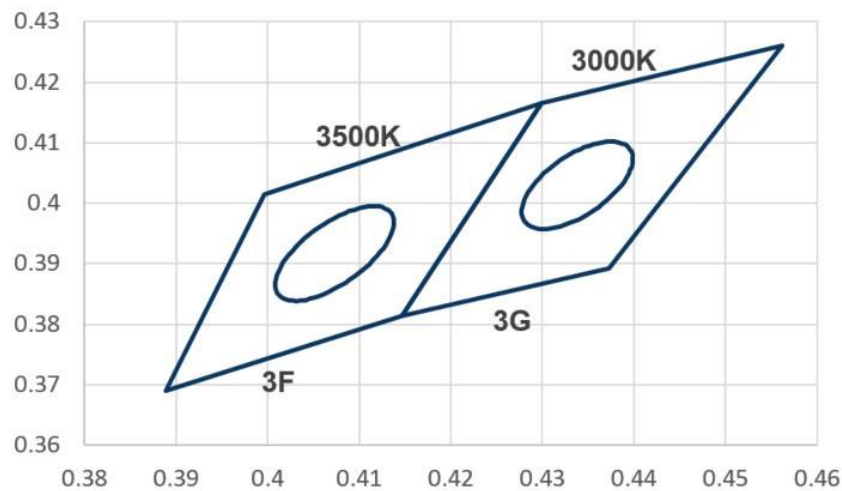
CIE Chromaticity Diagram (Nature white), $T_c=25^\circ\text{C}$



4000K 3 Step Ellipse

3E				
x	y	a	b	theta
0.3818	0.3797	0.0094	0.004	53

CIE Chromaticity Diagram (Warm white), $T_c=25^\circ\text{C}$



3500K 3 Step Ellipse

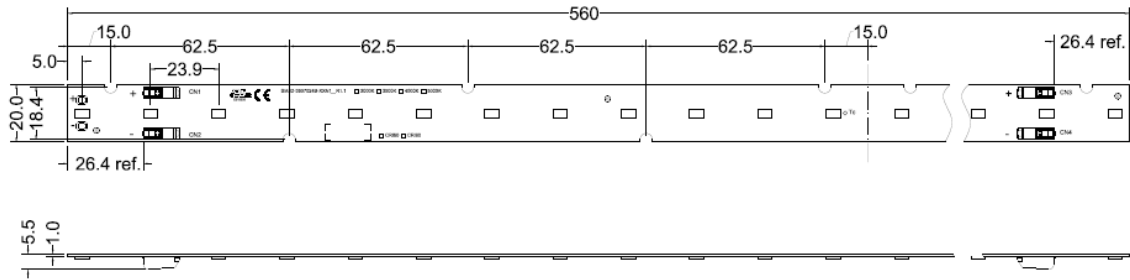
3F				
x	y	a	b	theta
0.4073	0.3917	0.0093	0.0041	53

3000K 3 Step Ellipse

3G				
x	y	a	b	theta
0.4338	0.4030	0.0085	0.0041	53

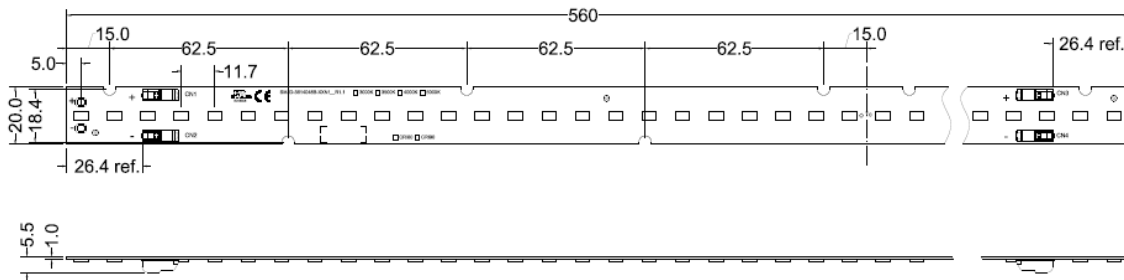
Mechanical Dimensions

SMJD-3607024B-XXN1



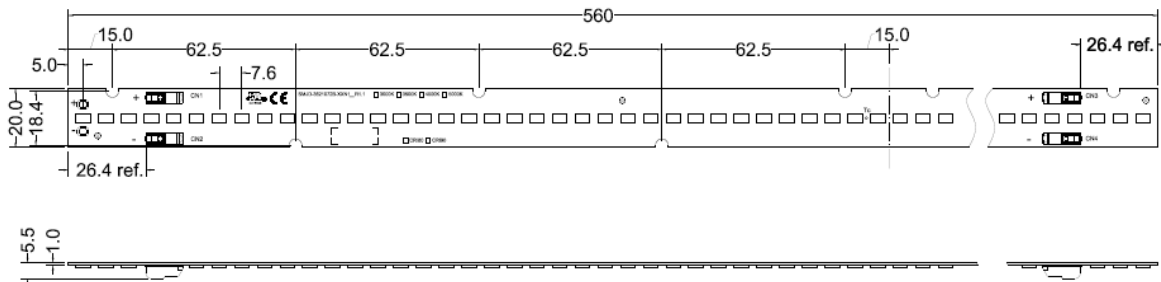
Dimension	Specification	Tolerance	Unit
Module Length	560	±0.5	mm
Module Width	20	±0.3	
Module Height	5.5	±0.3	
PCB Thickness	1.0	±0.1	

SMJD-3614048B-XXN1



Dimension	Specification	Tolerance	Unit
Module Length	560	±0.5	mm
Module Width	20	±0.3	
Module Height	5.5	±0.3	
PCB Thickness	1.0	±0.1	

SMJD-3621072B-XXN1



Dimension	Specification	Tolerance	Unit
Module Length	560	±0.5	mm
Module Width	20	±0.3	
Module Height	5.5	±0.3	
PCB Thickness	1.0	±0.1	

Product Nomenclature:

*Please refer to the following chart

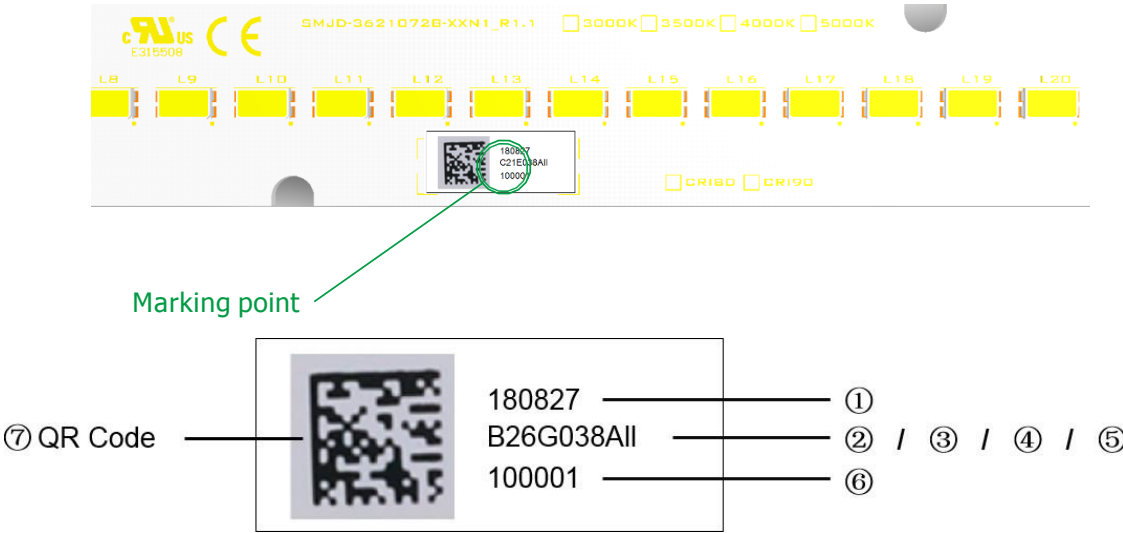
S M J D - 36 07 024 B - XX N 1										
Seoul DC Module										
Voltage		Power		LED Qty			Type	Custom	Dimming	Etc
3	6	0	7	0	2	4	B	XX	N	1
0 0V	0 0V	0 0W	0 0W	0 0ea	0 0ea	0 0ea	B 5630D	XX ref	N Norm	1 vers
1 10V	1 1V	1 10W	1 1W	1 100ea	1 10ea	1 1ea			D Dim	
2 20V	2 2V	2 20W	2 2W	2 200ea	2 20ea	2 2ea			E etc	
3 30V	3 3V	3 30W	3 3W	3 300ea	3 30ea	3 3ea				
-	-	-	-	-	-	-				
9 90V	9 9V	9 90W	9 9W	9 900ea	9 90ea	9 9ea				
A 100V		A 100W		A 1000ea						
B 110V		B 110W		B 1100ea						
-		-		-						
Z 350V		Z 350W		Z 3500ea						

Product Nomenclature: Binning

*Please refer to the following chart

00 B26 G03 8 ALL				
Lens Type	Flux Bin	CCT Bin	CRI Bin	VF Bin
00	B26	G03	8	ALL
00 No Lens	B26 1260 lm	G03 3000k - 3 step	8 CRI 80	All 33.6 ~ 35.4V _{DC}
		F03 3500k - 3 step		
		E03 4000k - 3 step		
		C03 5000k - 3 step		

Marking Information



No.	Item	Information	Digits	Remark
①	Date	YYMMDD	6 Digit	SMT date
②	Flux ⁽¹⁾	B26	3 Digit	B26=1260lm
③	CCT	X03 3-step Mixing	3 Digit	X=C,E,F,G
④	CRI	8	1 Digit	CRI=80
⑤	V _F	All	3 Digit	
⑥	Lot No.	1	1 Digit	0~9,A~Z
	Sequence No.	00001	5 Digit	00001 ~ 99999
⑦	QR Code	QR Code	-	Please refer to below table

Note:

*Flux Bin - please refer to following chart for definitions:

Flux Bin Definitions

Symbol	lm	Symbol	lm	Symbol	lm	Symbol	lm
A50	500	D50	3500	G50	6500	J50	9500
B50	1500	E50	4500	H50	7500	K20	10200
C50	2500	F50	5500	I50	8500	L00	11000

Module QR Code Information

 QR Code Information								
Items	Factory	SAP Code	SMT Date	MP information	Line No.	Lot No.	Product	Note
Digits	1 Digit	7 Digits	6 Digits	10 Digits	1 Digit	1 Digit	5 Digits	In Total 31 Digits
Information	*	*****	YYMMDD	B26G03 8ALL	1~9, A~Z	1~9, A~Z	00001	

Notes:

- 1 QR coded information shall include the fields described in the table above.
- 2 Minimum size of QR code shall be 4.5 mm x 4.5 mm and a minimum QR code grade of 'C'.
* 'A' grading is preferred.
- 3 If the component is small to have a full label, it is acceptable to have only the QR code in minimum size of 6 mm by 6 mm printed on a label.
- 4 The length of the QR code is 31 digits and includes all characters combined without spaces.

Example: *****180827 B26G038ALL11100001

Label Information

PO Number 	XXXXXX ⁽¹⁾
Supplier Part Number 	SMJD-3607024B-XXN100B26G038ALL ⁽²⁾
Bin Code 	B26G038ALL ⁽³⁾
Quantity 	XX
Country of Origin 	XX ⁽⁴⁾
Date Code 	YYYYWW ⁽⁵⁾
Lot Code 	YYMDDXXXXX- XXXXXXXX ⁽⁶⁾
	SEOUL SEMICONDUCTOR CO.,LTD.

Notes:

- [1] This is customer's PO Number
- [2] Please refer to SPEC page 10 (30 digit code)
- [3] Please refer to SPEC page 10
- [4] Country of Origin: 2 digit code . For example : Chinese Code: CN
- [5] Date Code : YYYYWW : Packing Date: Year + Week
- [6] Lot Code :
Initial of manufacture is refer to the 2D code rule.
YYMDD : Packing Date (Oct. : A, Nov. : B, Dec. : C)
X : Initial of Manufacturer
XXXX : Sealing Pack No.
XXXXXXX : SSC SAP Code
- [7] It is attached to the top left corner of the box.

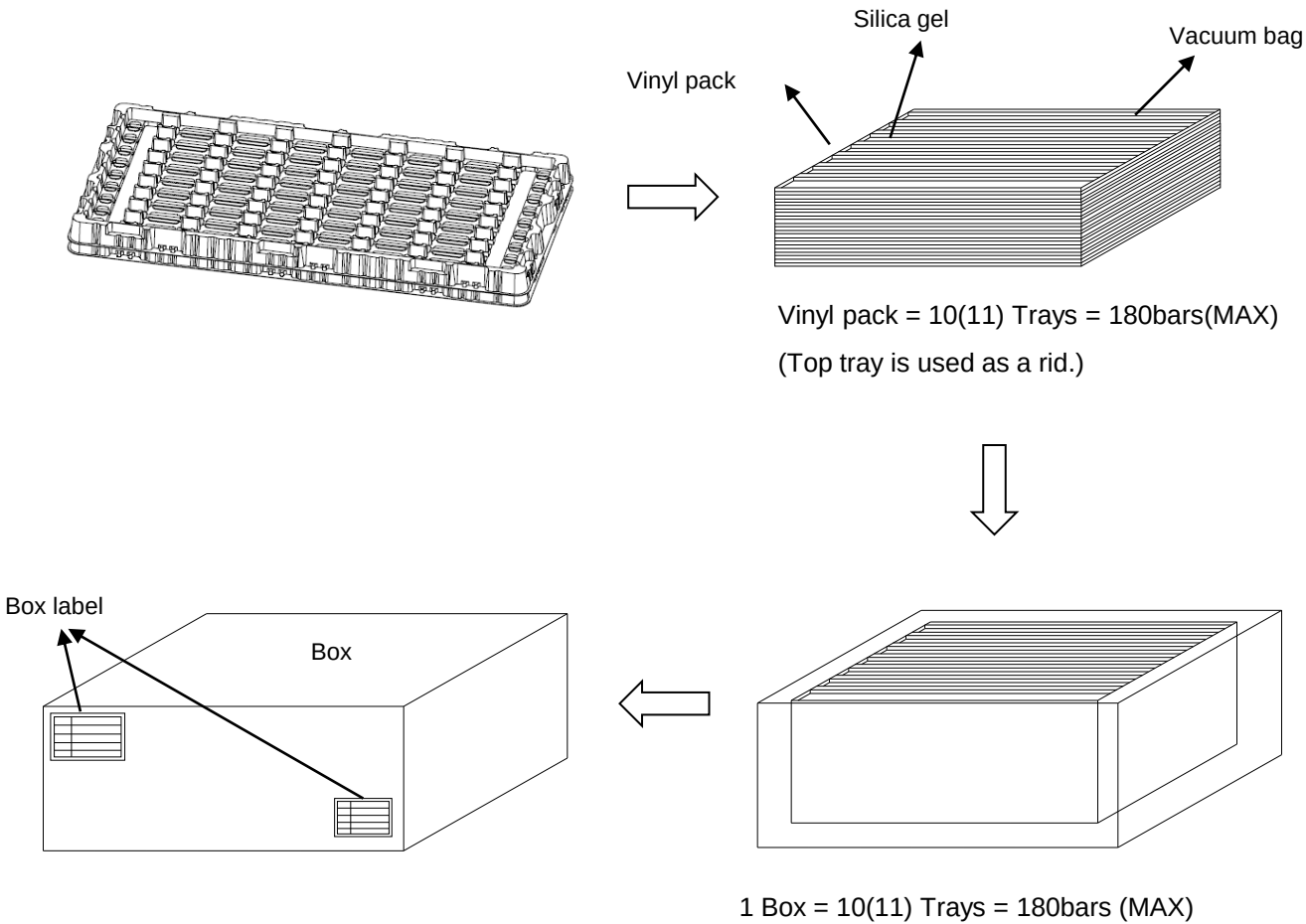
TOTAL Quantity  XX  SEOUL SEMICONDUCTOR CO.,LTD.

Notes:

- [1] Attached to the bottom right corner of the carton box.

Packaging Specification

Model	Tray		Box		Pallet	
	Size (mm)	Q'ty per tray	Size (mm)	Q'ty per box	Size (mm)	Q'ty per pallet
SMJD-3607024B-XXN1						
SMJD-3614048B-XXN1	610 x 300 x 30	18	625*315*215	180	1000*1000	3600
SMJD-3621072B-XXN1						



Storage before use

1. When storing devices for a long period of time before usage, please following these guidelines.
 - The devices should be stored in the anti-static bag that it was shipped in from Seoul-Semiconductor with opening
 - If the anti-static bag has been opened, re-seal preventing air and moisture from being present in the bag.



SEOUL SEMICONDUCTOR

Company Information

Seoul Semiconductor (SeoulSemicon.com) manufactures and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", deep UV LEDs, "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology", a proprietary family of high-voltage LEDs. The company's broad product portfolio includes a wide array of package and device choices such as Acrich, high-brightness LEDs, mid-power LEDs, side-view LEDs, through-hole type LED lamps, custom displays, and sensors. The company is vertically integrated from epitaxial growth and chip manufacture in its fully owned subsidiary, Seoul Viosys, through packaged LEDs and LED modules in three Seoul Semiconductor manufacturing facilities. Seoul Viosys also manufactures a wide range of unique deep-UV wavelength devices.

Legal Disclaimer

Information in this document is provided in connection with Seoul Semiconductor products. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Seoul Semiconductor hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party. The appearance and specifications of the product can be changed to improve the quality and/or performance without notice.